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October 2016

ON Semiconductor® FFSH30120ADN_F155 Silicon Carbide Schottky Diode 1200 V, 30 A

Features

- Max Junction Temperature 175 °C
- Avalanche Rated 145 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- · Ease of Paralleling
- No Reverse Recovery / No Forward Recovery

Applications

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits

Description

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.



Absolute Maximum Ratings T_C = 25 °C unless otherwise noted. (per leg)

Paramete	FFSH30120ADN_F155	Unit	
Peak Repetitive Reverse Voltage	1200	V	
Single Pulse Avalanche Energy	145	mJ	
Continuous Rectified Forward Current @ T	15* / 30**	А	
Non-Repetitive Peak Forward Surge Cur-	T _C = 25 °C, 10 μs	1030	А
rent	T _C = 150 °C, 10 μs	990	А
Non-Repetitive Forward Surge Current	Half-Sine Pulse, t _p = 8.3 ms	125	А
Repetitive Forward Surge Current	Half-Sine Pulse, t _p = 8.3 ms	50	А
Power Dissipation	T _C = 25 °C	195	W
	T _C = 150 °C	32	W
Operating and Storage Temperature Range	-55 to +175	°C	
TO247 Mounting Torque, M3 Screw	60	Ncm	
naracteristic			
Paramete	FFSH30120ADN_F155	Unit	
Thermal Resistance, Junction to Case, Max	0.77* / 0.32**	°C/W	
	Peak Repetitive Reverse Voltage Single Pulse Avalanche Energy Continuous Rectified Forward Current @ T Non-Repetitive Peak Forward Surge Current Non-Repetitive Forward Surge Current Repetitive Forward Surge Current Power Dissipation Operating and Storage Temperature Range TO247 Mounting Torque, M3 Screw Paramete	$\label{eq:sigma} \begin{array}{ c c c c } \hline Single Pulse Avalanche Energy & (Note 1) \\ \hline Continuous Rectified Forward Current @ Tc < 148 °C \\ \hline Non-Repetitive Peak Forward Surge Current & T_C = 25 °C, 10 \ \mu s \\ \hline T_C = 150 °C, 10 \ \mu s \\ \hline Non-Repetitive Forward Surge Current & Half-Sine Pulse, t_p = 8.3 \ ms \\ \hline Repetitive Forward Surge Current & Half-Sine Pulse, t_p = 8.3 \ ms \\ \hline Power Dissipation & \hline T_C = 25 °C \\ \hline T_C = 150 °C \\ \hline T_C = 150 °C \\ \hline T_C = 150 °C \\ \hline \end{array}$	$\begin{tabular}{ c c c c c } \hline Peak Repetitive Reverse Voltage & 1200 \\ \hline Single Pulse Avalanche Energy & (Note 1) & 145 \\ \hline Continuous Rectified Forward Current @ Tc < 148 °C & 15* / 30** \\ \hline Non-Repetitive Peak Forward Surge Current & T_C = 25 °C, 10 \mbox{ \mus } & 1030 \\ \hline T_C = 150 °C, 10 \mbox{ \mus } & 990 \\ \hline Non-Repetitive Forward Surge Current & Half-Sine Pulse, t_p = 8.3 \mbox{ ms } 125 \\ \hline Repetitive Forward Surge Current & Half-Sine Pulse, t_p = 8.3 \mbox{ ms } 50 \\ \hline T_C = 25 °C & 195 \\ \hline T_C = 150 °C & 32 \\ \hline Operating and Storage Temperature Range & -55 \mbox{ to +175} \\ \hline TO247 \mbox{ Mounting Torque, M3 Screw } & 60 \\ \hline \end{tabular}$

* Per leg, ** Per Device

Part Number		Top Mark	Package	Packing Method	Reel Size	Tape Width	Qua	antity	
FFSH30120ADN_F155		FFSH30120ADN	TO-247 Long Lead	Tube	N/A	N/A	30 units		
Electric	al Chara	cteristics T _C	= 25 °C unless other	wise noted. (per leg)					
Symbol		Parameter		Test Conditions	Mir	n. Typ.	Max.	Unit	
V _F			I _F = 1	5 A, T _C = 25 ^o C	-	1.45	1.75		
	Forward Voltage		I _F = 1	5 A, T _C = 125 °C	-	1.7	2	V	
			I _F = 1	5 A, T _C = 175 ^o C	-	2	2.4		
I _R F			V _R =	1200 V, T _C = 25 ^o C	-	-	200		
	Reverse Ci			1200 V, T _C = 125 °C	-	-	300	0 μΑ	
			V _R =	1200 V, T _C = 175 °C	-	-	400		
Q _C	Total Capacitive Charge		V = 80	00 V	-	95	-	nC	
С			V _R =	1 V, f = 100 kHz	-	936	-		
	Total Capacitance		$V_R = $	400 V, f = 100 kHz	-	86	-	pF	
			$V_R = 1$	300 V, f = 100 kHz	-	68	-	1	

Notes: 1: EAS of 145 mJ is based on starting T_J = 25 °C, L = 0.5 mH, I_{AS} = 24 A, V = 150 V.

Figure 1. Forward Characteristics

Typical Characteristics T_J = 25 °C unless otherwise noted (per leg).

30 T_J = -55 °C T_J = 25 °C I_F, FORWARD CURRENT (A) T_J = 75 °C 20 T_J = 125 °C T_J = 175 °C 10 0 0 2 3 1 4 V_F, FORWARD VOLTAGE (V)

Figure 3. Reverse Characteristics

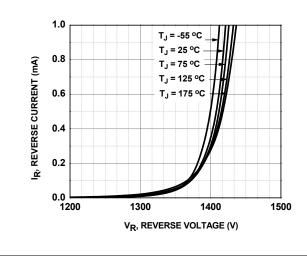
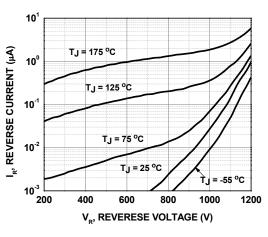
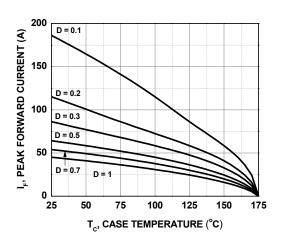
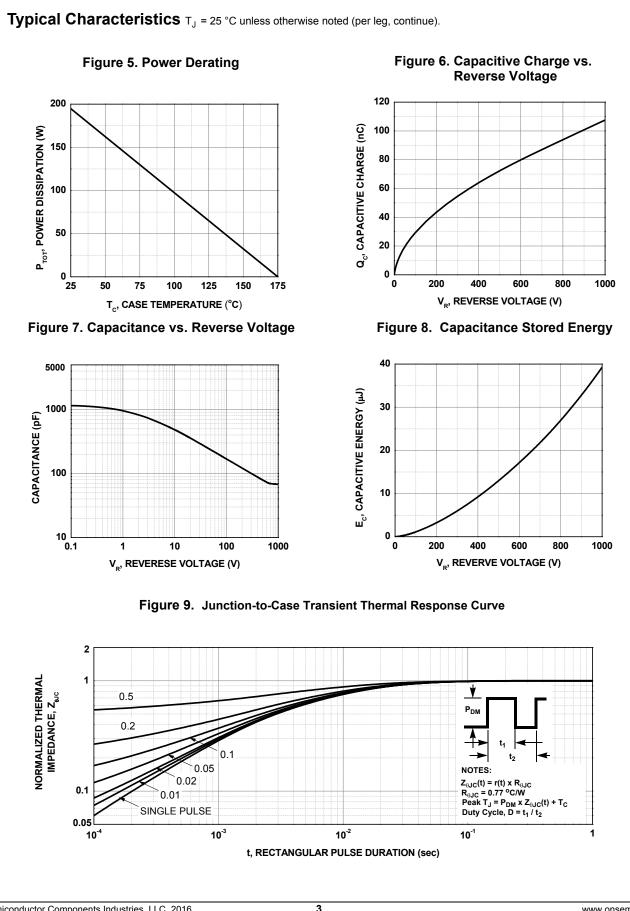


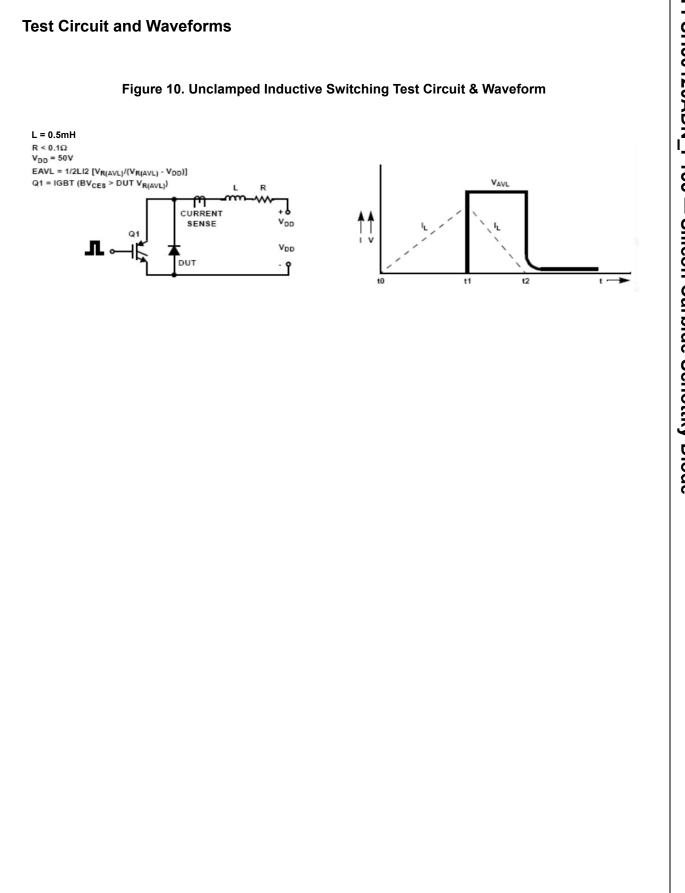
Figure 2. Reverse Characteristics

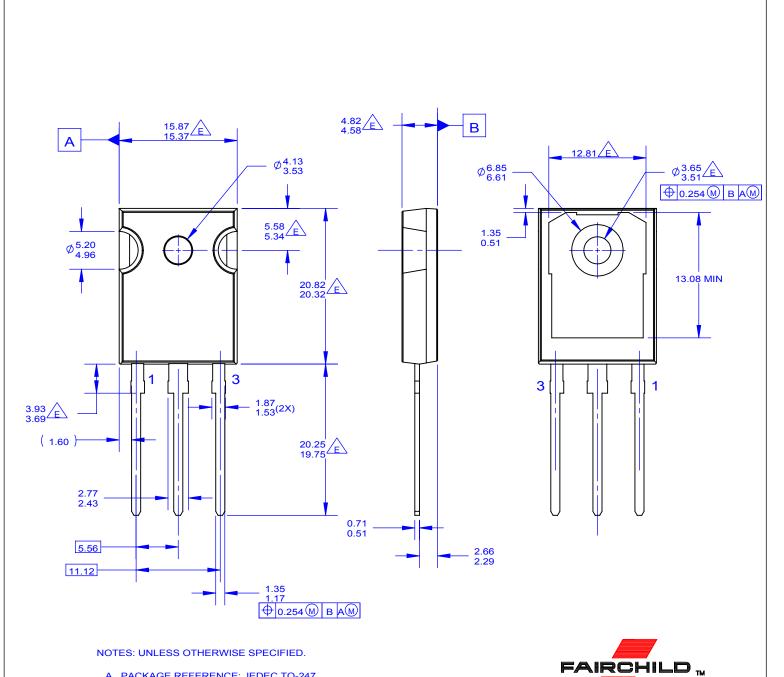












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